



PIMN32-Q

50 V, 500 mA NPN/NPN Resistor-Equipped double Transistor (RET); R1 = 2.2 k Ω , R2 = 10 k Ω

16 February 2022

Product data sheet

1. General description

NPN/NPN Resistor-Equipped double Transistor (RET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: PIMP32-Q

NPN/PNP complement: PIMC32-Q

2. Features and benefits

- 500 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Digital applications
- Cost-saving alternative to BC817 series in digital applications
- Control of IC inputs
- Switching loads

4. Quick reference data

Table 1. Quick reference data

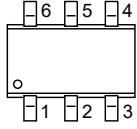
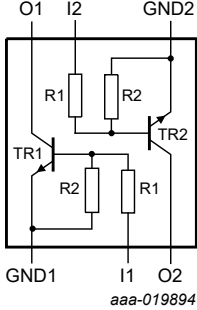
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Per transistor						
V _{CEO}	collector-emitter voltage	open base	-	-	50	V
I _O	output current		-	-	500	mA
R1	bias resistor 1 (input)	[1]	1.54	2.2	2.86	k Ω
R2/R1	bias resistor ratio	[1]	4.1	4.55	5	

[1] See section "Test information" for resistor calculation and test conditions.

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1	 <p>SC-74; TSOP6 (SOT457)</p>	 <p>aaa-019894</p>
2	I1	input (base) TR1		
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	I2	input (base) TR2		
6	O1	output (collector) TR1		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PIMN32-Q	SC-74; TSOP6	plastic, surface-mounted package (SC-74; TSOP6); 6 leads	SOT457

7. Marking

Table 4. Marking codes

Type number	Marking code
PIMN32-Q	4G

8. Limiting values

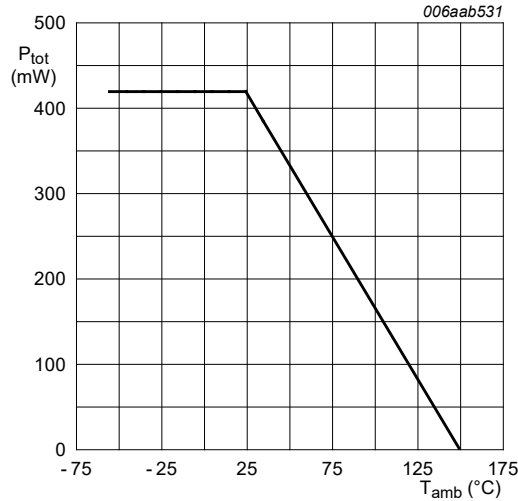
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per transistor					
V_{CBO}	collector-base voltage	open emitter	-	50	V
V_{CEO}	collector-emitter voltage	open base	-	50	V
V_{EBO}	emitter-base voltage	open collector	-	5	V
V_i	input voltage		-5	12	V
I_o	output current		-	500	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ }^\circ\text{C}$	[1]	290	mW
Per device					
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ }^\circ\text{C}$	[1]	420	mW
T_j	junction temperature		-	150	$^\circ\text{C}$
T_{amb}	ambient temperature		-55	150	$^\circ\text{C}$
T_{stg}	storage temperature		-65	150	$^\circ\text{C}$

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 μm copper, tin-plated and standard footprint.

50 V, 500 mA NPN/NPN Resistor-Equipped double Transistor (RET); R1 = 2.2 kΩ, R2 = 10 kΩ



FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint

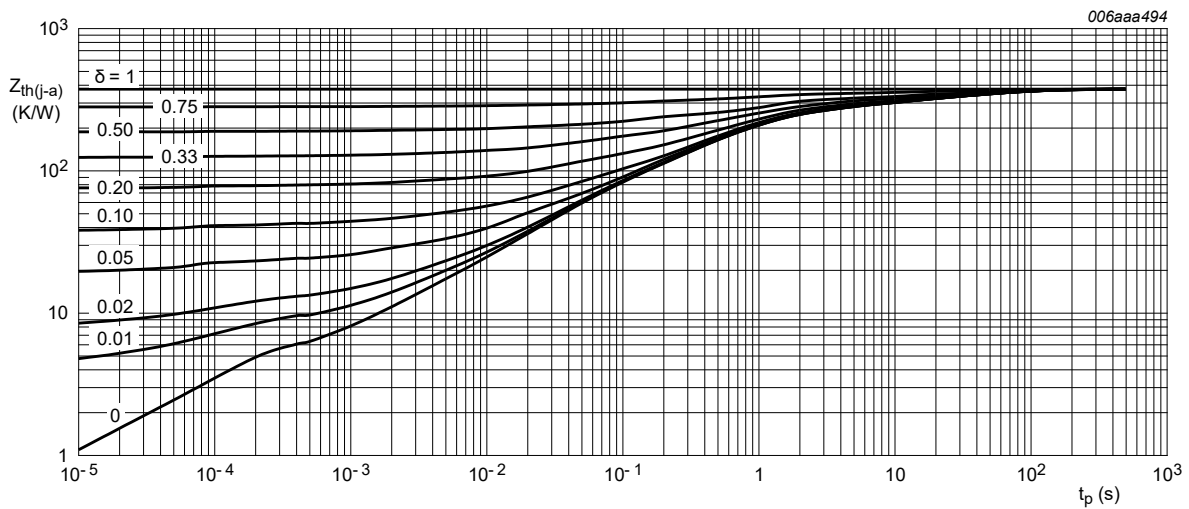
Fig. 1. Per device: Power derating curve

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	432	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	105	K/W
Per device							
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	298	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35μm copper, tin-plated and standard footprint

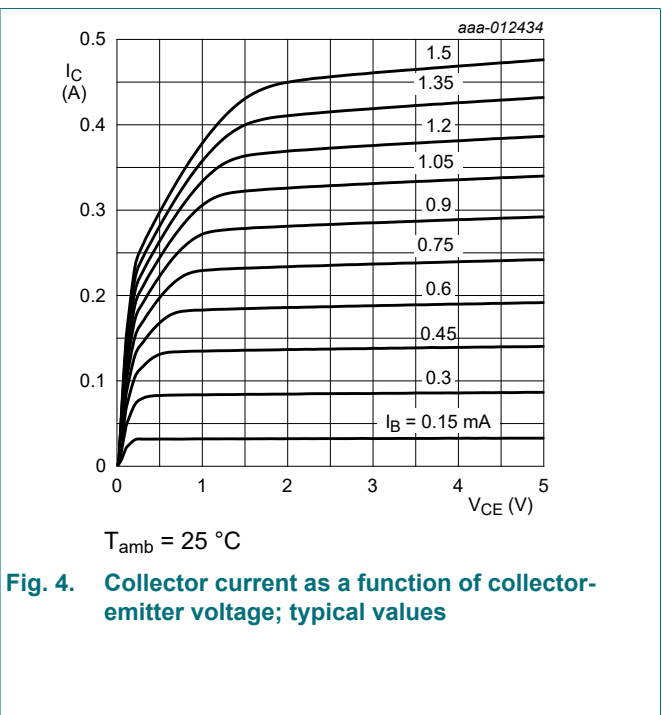
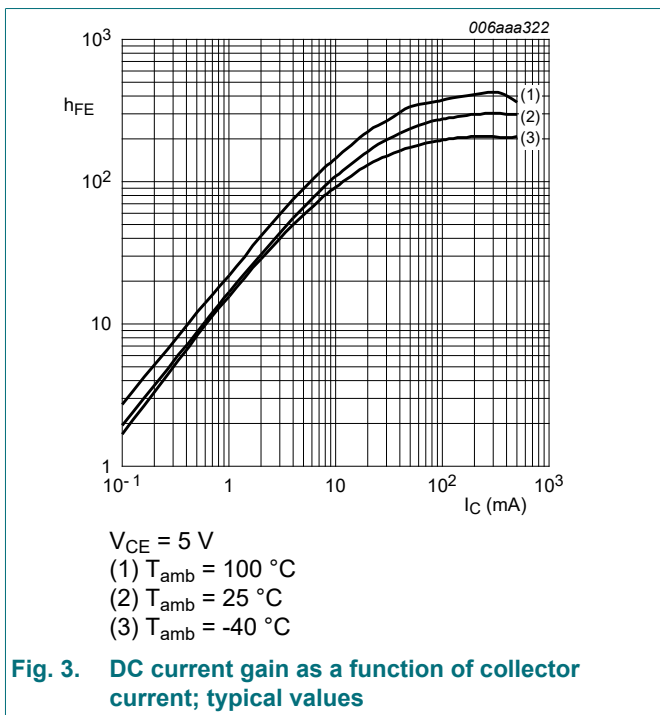
Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

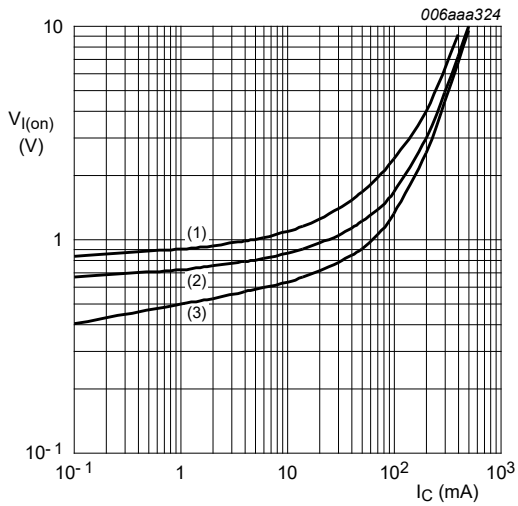
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Per transistor						
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \mu A; I_E = 0 A; T_{amb} = 25 \text{ }^\circ C$	50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 10 \text{ mA}; I_B = 0 A; T_{amb} = 25 \text{ }^\circ C$	50	-	-	V
I_{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 A; T_{amb} = 25 \text{ }^\circ C$	-	-	100	nA
I_{CEO}	collector-emitter cut-off current	$V_{CE} = 50 \text{ V}; I_B = 0 A; T_{amb} = 25 \text{ }^\circ C$	-	-	0.5	μA
I_{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_C = 0 A; T_{amb} = 25 \text{ }^\circ C$	-	-	0.65	mA
h_{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_C = 50 \text{ mA}; T_{amb} = 25 \text{ }^\circ C$	70	-	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 50 \text{ mA}; I_B = 2.5 \text{ mA}; T_{amb} = 25 \text{ }^\circ C$	-	-	100	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_C = 100 \mu A; T_{amb} = 25 \text{ }^\circ C$	0.4	0.65	1	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_C = 20 \text{ mA}; T_{amb} = 25 \text{ }^\circ C$	0.5	0.95	1.4	V
R1	bias resistor 1 (input)		[1]	2.2	2.86	kΩ
R2/R1	bias resistor ratio		[1]	4.55	5	
C_c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 A; i_e = 0 A; f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^\circ C$	-	7	-	pF
f_T	transition frequency	$V_{CE} = 5 \text{ V}; I_C = 50 \text{ mA}; f = 100 \text{ MHz}; T_{amb} = 25 \text{ }^\circ C$	[2]	225	-	MHz

[1] See section "Test information" for resistor calculation and test conditions.
 [2] Characteristics of built-in transistor

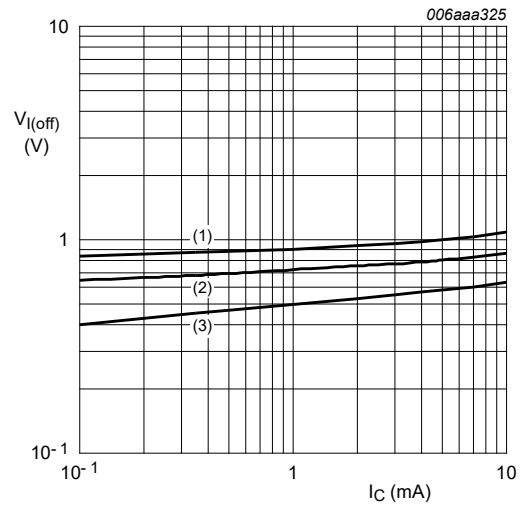


50 V, 500 mA NPN/NPN Resistor-Equipped double Transistor (RET); R1 = 2.2 kΩ, R2 = 10 kΩ



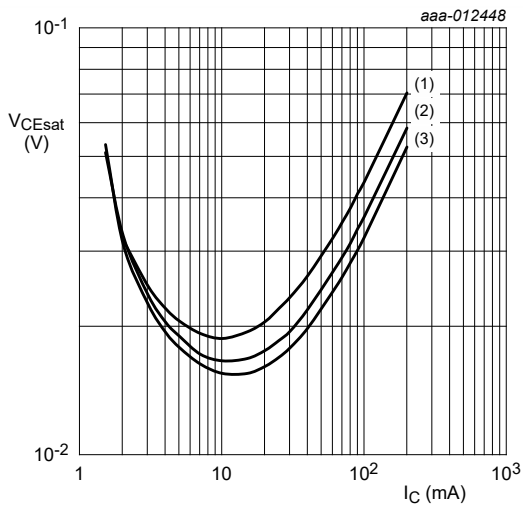
$V_{CE} = 0.3 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 5. On-state input voltage as a function of collector current; typical values



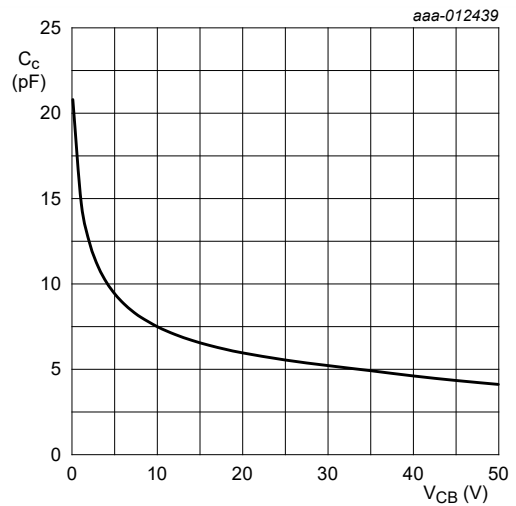
$V_{CE} = 5 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 6. Off-state input voltage as a function of collector current; typical values



$I_C/I_B = 20$
 (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = -40 \text{ }^\circ\text{C}$

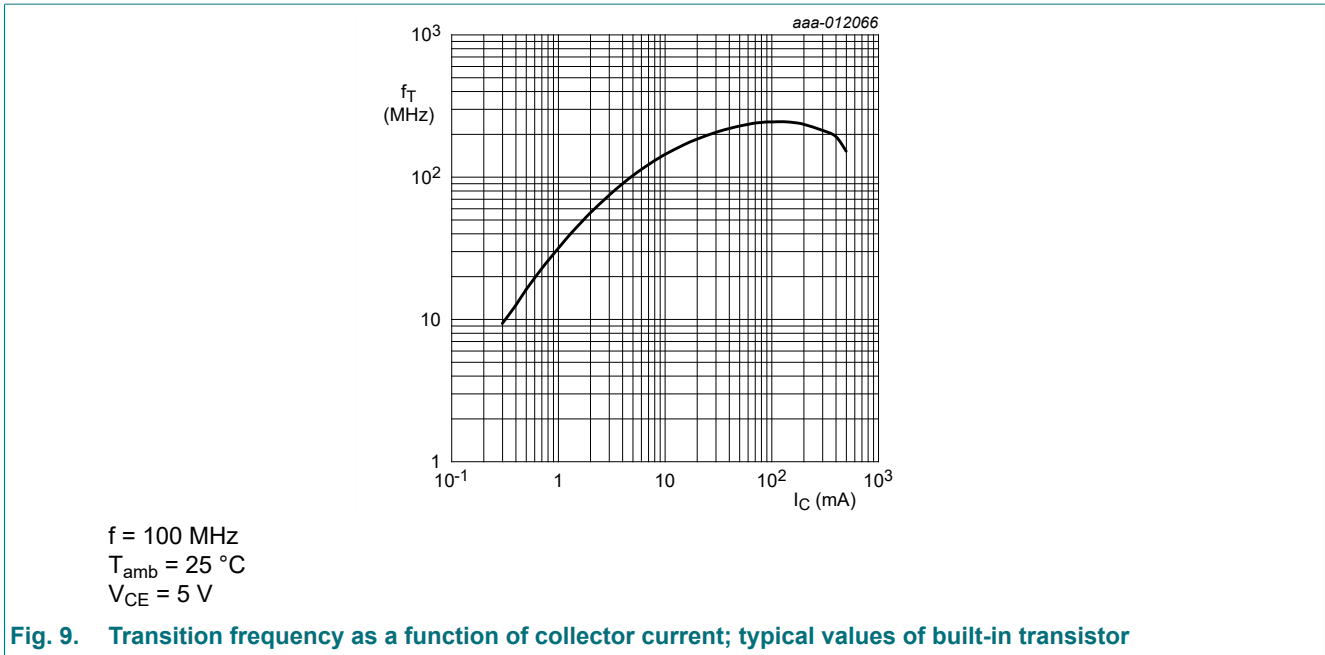
Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



$f = 1 \text{ MHz}$
 $T_{amb} = 25 \text{ }^\circ\text{C}$

Fig. 8. Collector capacitance as a function of collector-base voltage; typical values

50 V, 500 mA NPN/NPN Resistor-Equipped double Transistor (RET); R1 = 2.2 kΩ, R2 = 10 kΩ



11. Test information

Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I_{I2}) - V(I_{I1})}{I_{I2} - I_{I1}}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I_{I4}) - V(I_{I3})}{R1 \cdot (I_{I4} - I_{I3})} - 1$$

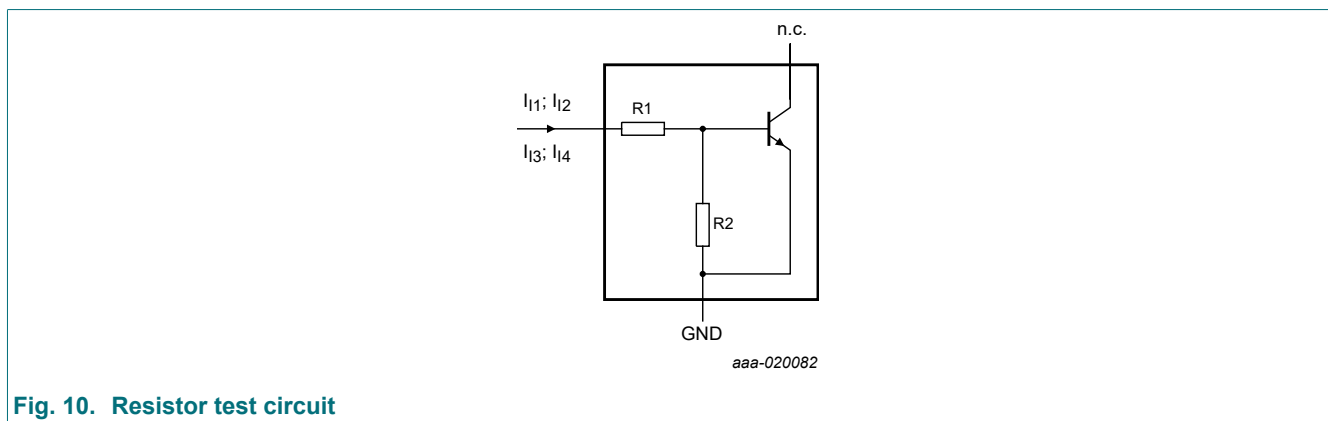


Fig. 10. Resistor test circuit

Resistor test conditions

Table 8. Resistor test conditions

R1 (kΩ)	R2 (kΩ)	Test conditions			
		I _{I1}	I _{I2}	I _{I3}	I _{I4}
2.2	10	0.7 mA	0.8 mA	-0.45 mA	-0.55 mA

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

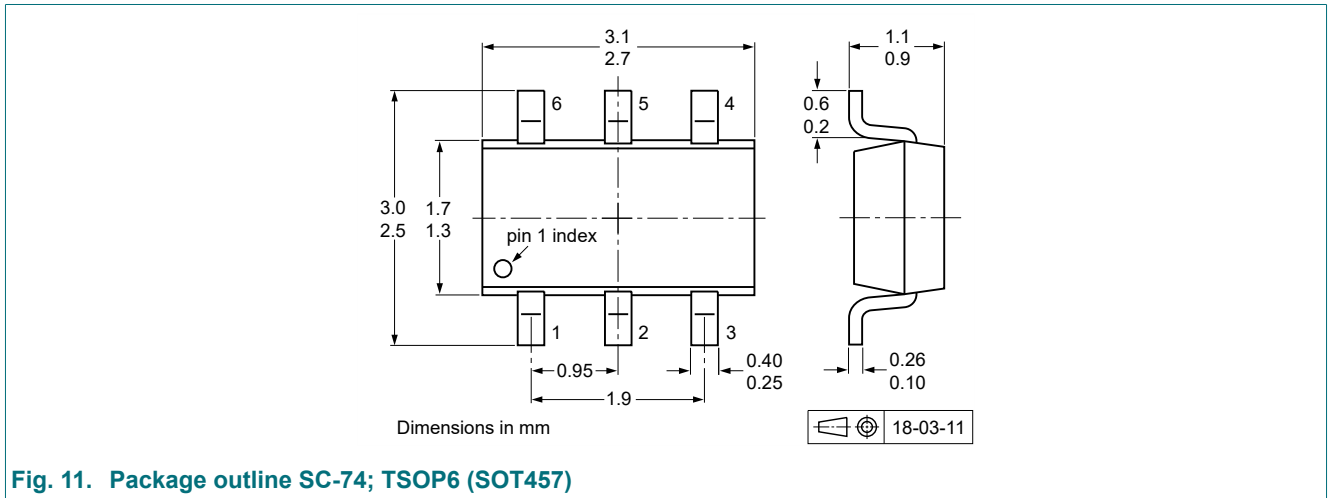


Fig. 11. Package outline SC-74; TSOP6 (SOT457)

13. Soldering

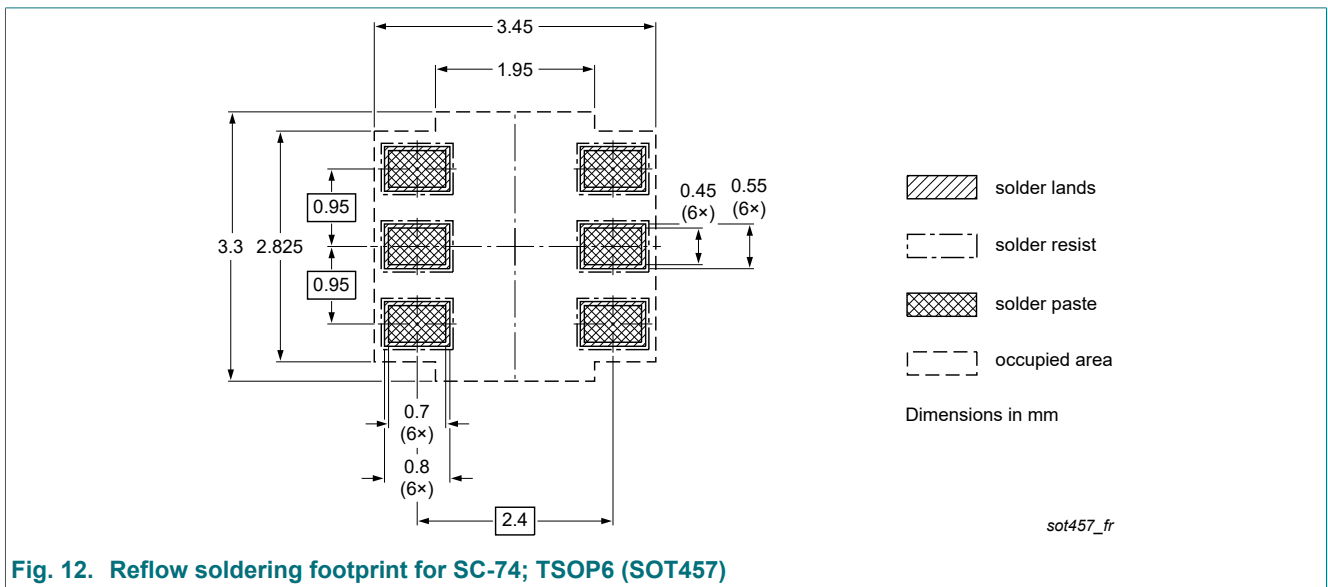


Fig. 12. Reflow soldering footprint for SC-74; TSOP6 (SOT457)

50 V, 500 mA NPN/NPN Resistor-Equipped double Transistor (RET); R1 = 2.2 kΩ, R2 = 10 kΩ

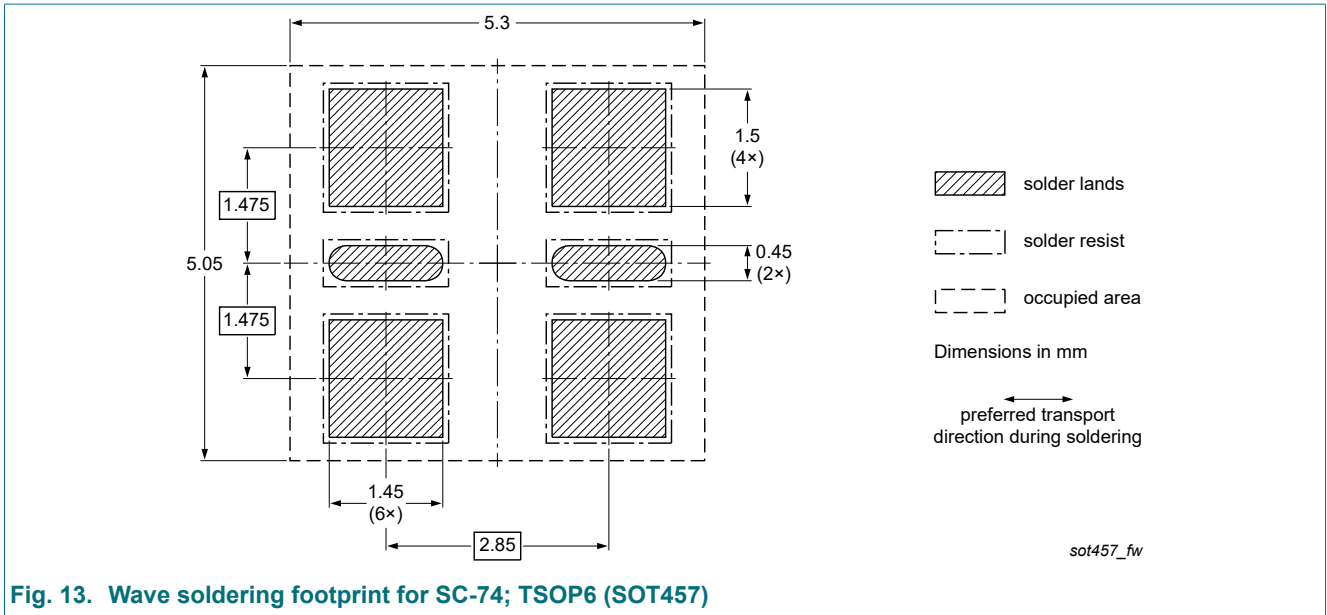


Fig. 13. Wave soldering footprint for SC-74; TSOP6 (SOT457)

50 V, 500 mA NPN/NPN Resistor-Equipped double Transistor (RET); R1 = 2.2 k Ω , R2 = 10 k Ω

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PIMN32-Q v.1	20220216	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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